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Influence of helium diffusion and aggregation on the variety of metal nanostructures under helium plasma irradiation <u>I. Mun¹</u>, A. Ito², K. Ibano¹, H.T. Lee¹, Y. Ueda¹

¹Graduate School of Engineering, Osaka University. ²Department of Helical Plasma Research, National Institute for Fusion Science.



- formation of fiber-like • The nanostructures tungsten(W) on and molybdenum(Mo) are observed after helium(He) plasma exposure.
- Their formation mechanism has not been understood well.
- The He bubble seems to have a influence on these nanostructures.

Purpose

- 1. To investigate microscopic relationship between metal and He
 - > Calculate variations of He binding energies using first principle calculation based on density functional theory (DFT)
- 2. To expand macroscopic simulation from DFT calculation result
 - > Developed He diffusion / aggregation simulation code based on kinetic Monte Carlo method (KMC)

Results of DFT calculation

Definition of He bind energy

 $E_{int}^{bind}(n) = -E_{tot} \left(Me_N He_n \right) - E_{tot} \left(Me_N \right) + E_{tot} \left(Me_N He_{n-1} \right) + E_{tot} \left(Me_N He_1 \right)$ $E_{vac}^{bind}(n) = -E_{tot} \left(Me_{N-1}He_n \right) - E_{tot} \left(Me_N \right) + E_{tot} \left(Me_{N-1}He_{n-1} \right) + E_{tot} \left(Me_N He_1 \right)$

The binding energies at interstitial sites The binding energies at a monovacancy







- > Investigate differences in formation of bubbles for each metal by KMC simulation

X In this study, KMC simulation is performed on interstitial sites of bcc metal, which does not consider vacancy.

Num. of trapped He atoms

Num. of trapped He atoms

- A metal with monovacancies has a higher binding energy
- A fiber-like nanostructure formable metal has a higher binding energy
- The peak position of the graph depends on the crystal structure

He bubble formation at each temperature in BCC metal's calculated by KMC simulation



• Appropriate temperature, at which bubbles tend to be large, varies from metal to metal (Agrees with experimental study) 0.0623

100

He diffusion: T-site

0

A cluster of 4 He atoms

 $E_{total}^4 = \varepsilon(1) + 2\varepsilon(2) + \varepsilon(3)$

0

 ≥ 0

 $\epsilon(2)$

- At low temperatures, since helium bonds are hard to break, it takes time to grow into large bubbles if small clusters are massive.
- At high temperature, the diffusion of helium will be fast and the bond will tear off easily, so the bubble will not grow

Та	0.0847
Nb	0.0996

0.0572

W

Mo

• It seems that the difference of bubble formation for each metal is greatly affected by the DFT calculation result

Average number of connection per elapsed time



He connection model in KMC

- Single He atom in BCC metal passes through the migration path on the right figure and is trapped at the T-site
- In DFT calculation, He tends to be trapped more easily at the T-site than the O-site when aggregated between the lattices and He is likely to be trapped in the vicinity of the second nearest T-site when viewed from the other He
- > In this KMC model, He jumps only between T-sites and is regarded as connecting when

KMC calculation method

- What is KMC:
 - \succ A method to make statistical behavior by repeating the particle jumping randomly between lattices with certain event
- What is KMC's event in this research:
 - > One helium at a certain T-site moves to some neighboring T-site
- The probability P_i that an event *i* occurs $P_i = P_0 \exp(-\frac{\Delta E}{k_B T}) \,[\mathrm{s}^{-1}]$

 $Regimes P_0 = 6D(T)/nl^2 \exp(-\Delta E_0/k_B T) [s^{-1}]$

 ΔE Barrier energy [eV] P_0 Prefactor Diffusion coefficient $D(\mathbf{T})$ Number of migration path for neach T-site Length of the migration path [m] ΔE_0 Activation energy [eV]

 $\Delta E_{migration}$

 $\Delta E_{connection}^k$

• A migration barrier energy $\Delta E_{migration}$ that a certain He does not connect to other He

 $\Delta E_{migration} = \Delta E_0$

• A detrap barrier energy ΔE_{detrap} that a certain ΔE_{detrap} He is connected to k other He

$$\Delta E_{detrap} = \Delta E_{migration} + \Delta E_{connect}^{k}$$

He is adjacent at the second nearest T-site.

How to obtain $\Delta E_{connect}^k$ from DFT calculation result

- We want to express $\Delta E_{connect}^k$ as a function of a certain number k of connections with another He.
- If there is cluster of n helium, the total energy that the cluster has E_{total}^{n} is $E_{total}^{n} = \sum_{i=1}^{n} \varepsilon(k_{i})$ atom [eV] • W
- $E_{int}^{bind}(n) = E_{total}^n E_{total}^{n-1}$
- Fitting $\varepsilon(k_i)$ in the form of ak + b

Metal	a [eV/atom]	<i>b</i> [eV]
W	0.2471	0.1853
Мо	0.2289	0.2067
Та	0.0687	-0.2532
Nb	0.1217	-0.0936



 $\succ \Delta E_0$ and $\Delta E_{connect}^{\kappa}$ are obtained by DFT

Summary

- By comparison between DFT calculation and experimental results, fiber-like nanostructures tend to be formed with metals with a higher binding energy.
- In order to investigate the relationship between the DFT calculation results and the He bubble formation tendency, we developed He aggregation / diffusion simulation code based on KMC.
- Temperature and material dependence of He bubble formation was observed by KMC simulation and there is an appropriate temperature range for the bubble grow.

Large bubbles are formed at temperatures as high as 1000 K or more for W and Mo with higher binding energy obtained by DFT

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